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|  | <h2>SI1406DH-T1-GE3</h2> |
| | <p>Hersteller-Teilenummer: SI1406DH-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N-CH 20V 3.1A SC-70-6</p> <p>Datenblätter:  SI1406DH-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 9000 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p> |
| <p>Image may be representation. See specs for product details.</p> | |

Spezifikationen

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|---|---|
| Teilenummer | SI1406DH-T1-GE3 |
| Hersteller | Vishay / Siliconix |
| Beschreibung | MOSFET N-CH 20V 3.1A SC-70-6 |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs , |
| Teilstatus | 9000 pcs Stock |
| Serie | TrenchFET® |
| Technologie | MOSFET (Metal Oxide) |
| Betriebstemperatur | -55°C ~ 150°C (TJ) |
| Befestigungsart | Surface Mount |
| Verpackung / Gehäuse | 6-TSSOP, SC-88, SOT-363 |
| Supplier Device-Gehäuse | SC-70-6 (SOT-363) |
| Verlustleistung (max) | 1W (Ta) |
| Typ FET | N-Channel |
| FET-Merkmal | - |
| Drain-Source-Spannung (Vdss) | 20V |
| Strom - Ununterbrochener Abfluss (Id) bei 25 °C | 3.1A (Ta) |
| Rds On (Max) @ Id, Vgs | 65 mOhm @ 3.9A, 4.5V |
| VGS (th) (Max) @ Id | 1.2V @ 250µA |
| Gate Charge (Qg) (Max) @ Vgs | 7.5nC @ 4.5V |
| Eingabekapazität (Ciss) (Max) @ Vds | - |
| Verpackung | Tape & Reel (TR) |










































SI1406DH-T1-GE3 ist neu im Original, Suche SI1406DH-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI1406DH-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI1406DH-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

| | | | |
|---|---|--|---|
|  SI1407DL-T1-GE3 V SI1407DL-T1-GE3 V |  SI1406DH-T1-E3 Vishay / Siliconix MOSFET N-CH 20V 3.1A SC70-6 |  SI1407DL VISHAY SI1407DL VISHAY |  SI1406DH-T1-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 20V 3.1A SC70-6 |
|  SI1407DL-T1 SILICON SI1407DL-T1 SILICON |  SI1406DH-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 20V 3.1A SC-70-6 |  SI1407DL-T1-E3 VISHAY SI1407DL-T1-E3 VISHAY |  SI1405DL-T1-GE3 Vishay / Siliconix MOSFET P-CH 8V 1.6A SC-70-6 |

heiße Teile

Mehr

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|  SI1403BDL-T1-GE3 |  SI1403CDL-T1-GE3 |  SI1403CDL-T1-GE3 | D SI1403DL |  SI1403DL-T1 |
|  SI1403DL-T1-E3 |  SI1403DL-T1-GE3 | D SI1404BDH-T1-E3 |  SI1404BDH-T1-E3 |  SI1404DH-T1 |
|  SI1404DH-T1-E3 |  SI1404DH-T1-GE3 |  SI1404DL-T1-GE3 |  SI1405BDH-T1-E3 |  SI1405BDH-T1-E3 |
| D SI1405BDH-T1-GE3 |  SI1405BDH-T1-GE3 |  SI1405DL-T1 |  SI1405DL-T1-E3 |  SI1405DL-T1-E3 |
|  SI1406DH |  SI1406DH-T1 |  SI1406DH-T1-E3 |  SI1406DH-T1-E3 |  SI1406DH-T1-GE3 |
|  SI1407DL |  SI1407DL-T1 | D SI1407DL-T1-E3 |  SI1407DL-T1-GE3 |  SI1410EDH |
|  SI1410EDH-T1 | D SI1410EDH-T1-E3 |  SI1410EDH-T1-E3 |  SI1410EDH-T1-GE3 |  SI1413DH-T1 |
|  SI1413EDH |  SI1413EDH-T1 |  SI1413EDH-T1-E3 |  SI1413EDH-T1-E3 |  SI1413EDH-T1-GE3 |
|  SI1413EDH-T1-GE3 |  SI1414DH-T1-GE3 |  SI1414DH-T1-GE3 | D SI1416EDH-T1-GE3 |  SI1416EDH-T1-GE3 |
|  SI1417DH-T1-E3 |  SI1417DH-T1-GE3 |  SI1417EDH-T1 |  SI1417EDH-T1-E3 |  SI1417EDH-T1-E3 |

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